



30V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

30 V

Current

1.6 A

Features

- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@1.6A<200m\Omega$
- R_{DS(ON)}, V_{GS}@2.5V, I_D@1.1A<270mΩ
- $R_{DS(ON)}$, $V_{GS}@1.8V$, $I_D@0.2A<570m\Omega$
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

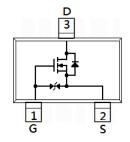
• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams







Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 8		
Continuous Drain Current(Note 4)		I _D	1.6	A	
Pulsed Drain Current ^(Note 1)		I _{DM}	6.4		
Power Dissipation	T _a =25°C	P_{D}	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient ^(Note 3,4)		Reja	100	°C/W	





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.5	0.78	1.3	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =1.6A	-	145	200	mΩ
		V _{GS} =2.5V, I _D =1.1A	-	185	270	
		V _{GS} =1.8V, I _D =0.2A	-	330	570	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	-	<u>+</u> 10	
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =1.6A, V _{GS} =4.5V ^(Note 1,2)	-	1.5	-	nC
Gate-Source Charge	Q_gs		-	0.3	-	
Gate-Drain Charge	Q_gd		-	0.3	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	93	-	pF
Output Capacitance	Coss		-	19	-	
Reverse Transfer Capacitance	Crss		-	6	-	
Turn-On Delay Time	td _(on)	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	6.4	-	
Turn-On Rise Time	tr	$V_{DD}=15V,\ I_{D}=1.6A,$ $V_{GS}=4.5V,$ $R_{G}=6\Omega^{(Note\ 1,2)}$	-	33	-	ns
Turn-Off Delay Time	td _(off)		-	37	-	
Turn-Off Fall Time	tf		-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	1	А
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.81	1.2	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

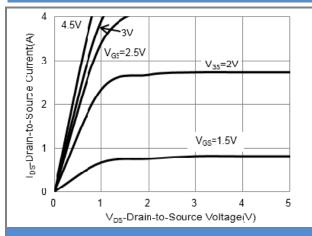


Fig.1 On-Region Characteristics

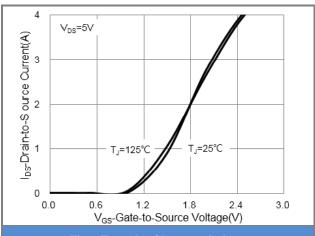


Fig.2 Transfer Characteristics

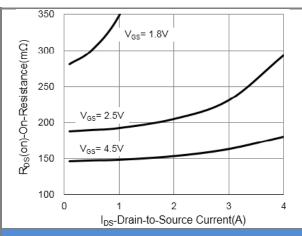


Fig.3 On-Resistance vs. Drain Current

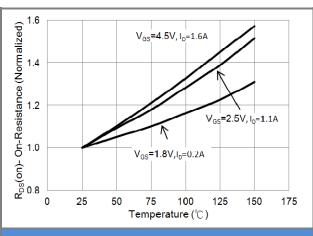
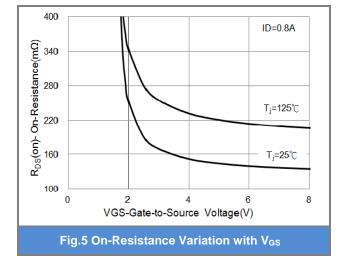
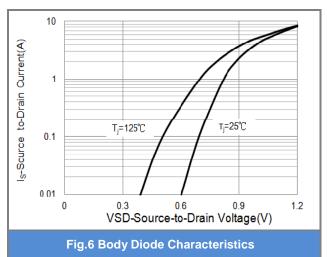


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

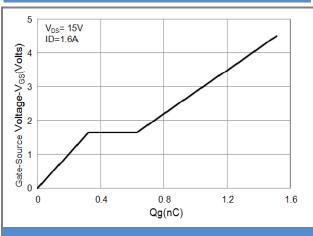


Fig.7 Gate-Charge Characteristics

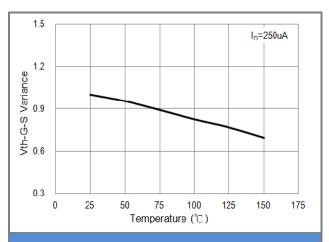


Fig.8 Threshold Voltage Variation with Temperature

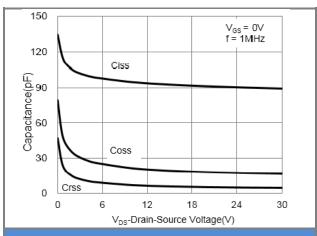


Fig.9 Capacitance vs. Drain-Source Voltage

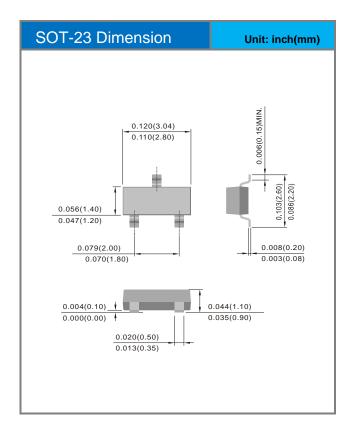


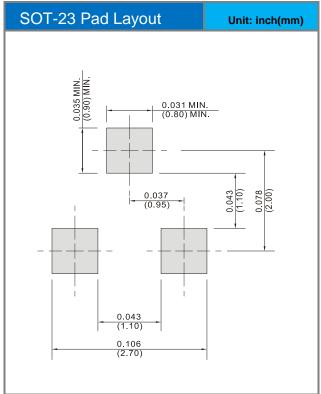


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3432-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A32	Halogen free

Packaging Information & Mounting Pad Layout









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